

# MAAM-010333



## Optical Node RF Amplifier 50 - 1000 MHz

Rev. V2

### Features

- -8 dBm to +2 dBm Optical Input Range
- Low Equivalent Input Noise (EIN): 3.2 pA/rtHz
- Single +5 V Bias
- 29 dB Gain at 55 MHz; 34 dB Gain at 1000 MHz
- 27 dB Gain Control Range
- +24 dBmV/ch Output at 550 MHz
- Lead-Free 4 mm PQFN-24LD Plastic Package
- Halogen-Free "Green" Mold Compound
- RoHS\* Compliant and 260°C Reflow Compatible

### Description

The MAAM-010333 provides high gain, low noise and low distortion amplification for optical node applications.

The MAAM-010333 is fabricated using M/A-COM Technology Solutions' low noise GaAs pHEMT technology in a lead-free 4 mm 24-lead package. The amplifier requires a minimal number of off-chip components resulting in a highly integrated low cost solution.

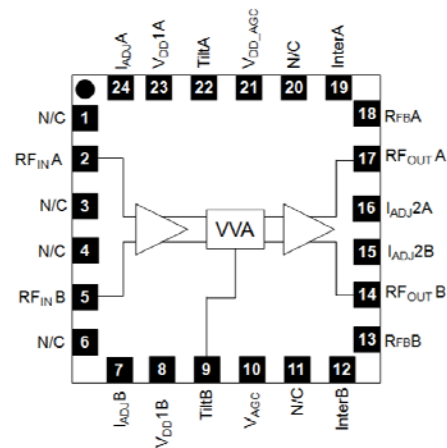
### Ordering Information <sup>1,2</sup>

Part Number	Package
MAAM-010333-TR1000	1000 Piece Reel
MAAM-010333-TR3000	3000 Piece Reel
MAAM-010333-001SMB	Sample Test Board

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts. Sample board is supplied with mounted photodiode.

\* Restrictions on Hazardous Substances,  
European Union Directive 2002/95/EC.

### Functional Schematic



### Pin Configuration <sup>3</sup>

Pin No.	Pin Name	Description
1	N/C	No Connection
2	RF_IN A	RF Input A
3	N/C	No Connection
4	N/C	No Connection
5	RF_IN B	RF Input B
6	N/C	No Connection
7	I_ADJ B	Current Adjust
8	V_DD1 B	+ 5V Bias Voltage
9	Tilt B	Tilt Connection
10	V_AGC	AGC Control Voltage: 0V to 3V
11	N/C	No Connection
12	Inter B	Interstage Pin
13	R_FB B	Feedback Resistor
14	RF_OUT B	RF Output B
15	I_ADJ2 B	Current Adjust
16	I_ADJ2 A	Current Adjust
17	RF_OUT A	RF Output A
18	R_FB A	Feedback Resistor
19	Inter A	Interstage Pin
20	N/C	No Connection
21	V_DD_AGC	+ 5V AGC Bias Voltage
22	Tilt A	Tilt Connection
23	V_DD1 A	+ 5V Bias Voltage
24	I_ADJ1	Current Adjust
25	Paddle	RF & DC Ground

3. The exposed pad centered on the package bottom must be connected to RF and DC ground.

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### Electrical Specifications<sup>4</sup>: $V_{DD} = +5$ Volts, $T_A = 25^\circ\text{C}$ , $Z_0 = 75 \Omega$

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Trans-Impedance Gain <sup>5,6</sup>	50 MHz	dB	26.5	29.0	30.5
	870 MHz		31.0	33.0	35.0
	1 GHz		31.5	34.0	35.5
Gain Tilt <sup>7</sup>	$V_{AGC} = +3$ V $V_{AGC} = 0$ V	dB	-	5 7	-
Gain Flatness <sup>8</sup>	$V_{AGC}$ : 0 to 3 V	dB		0.7	
Gain Control Range	50 MHz	dB	25.5	29.0	32.0
	870 MHz		23.0	26.0	29.0
	1 GHz		24.0	27.0	30.0
AGC Control Voltage Range	50 MHz - 1 GHz	V	0	-	+3
EIN <sup>6</sup>	50 MHz - 1 GHz	pA/rHz	-	3.2	-
Output Return Loss	50 MHz - 1 GHz	dB	-	18	-
CTB <sup>9</sup>	79 channels	dBc	-	-68	-
CSO <sup>9</sup>	79 channels	dBc	-	-65	-
Current	$V_{DD} = +5$ V	mA	225	260	295

4. Performance is specified using JDSU Photodiode EPM-745 or equivalent (EPM705) and output balun # MABA-009210-CT1760.

5.  $\text{Gain} = 20 \cdot \log(Z_T/75)$ , where  $Z_T = \text{Transconductance } (\Omega)$

6. Specified at maximum gain ( $V_{AGC} = +3.0$  V)

7. Positive gain slope from 50 MHz to 1 GHz (tilt of best fit straight line from 50 MHz to 1 GHz)

8. Flatness defined as peak-peak deviation from best fit straight line.

9. Optical Input Power Range: -8 dBm to +2 dBm; 79 channels

O<sub>MI</sub> = 3.5%; P<sub>out</sub> = +24 dBmV/ch at 550 MHz

P<sub>OUT</sub> = +22.5 dBmV/ch at 55 MHz; +24 dBmV/ch at 550 MHz

### Absolute Maximum Ratings<sup>10,11,12</sup>

Parameter	Absolute Maximum
Input Power	+3 dBm Optical
Operating Voltage	+15 volts
AGC Voltage	+5 volts
Operating Temperature	-40°C to +85°C
Junction Temperature <sup>13</sup>	+150°C
Storage Temperature	-65°C to +150°C

10. Exceeding any one or combination of these limits may cause permanent damage to this device.

11. M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.

12. Operating at nominal conditions with  $T_J \leq +150^\circ\text{C}$  will ensure  $\text{MTTF} > 1 \times 10^6$  hours.

13. Junction Temperature ( $T_J$ ) =  $T_C + \Theta_{jc} \cdot ((V \cdot I) - (P_{OUT} - P_{IN}))$

Typical thermal resistance ( $\Theta_{jc}$ ) = 19° C/W.

a) For  $T_C = 25^\circ\text{C}$ ,

$T_J = 53^\circ\text{C} @ 5$  V, 295 mA

b) For  $T_C = 85^\circ\text{C}$ ,

$T_J = 112^\circ\text{C} @ 5$  V, 295 mA

### Handling Procedures

Please observe the following precautions to avoid damage:

### Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

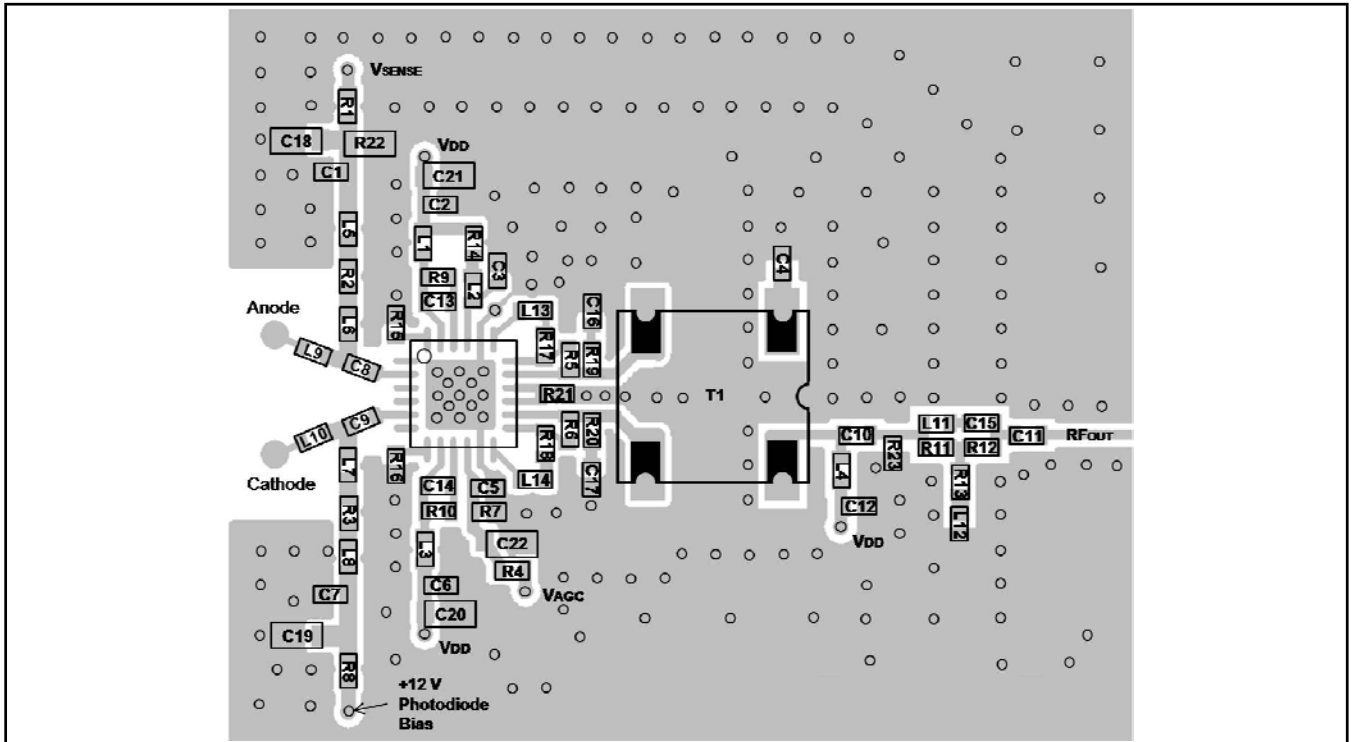
# MAAM-010333



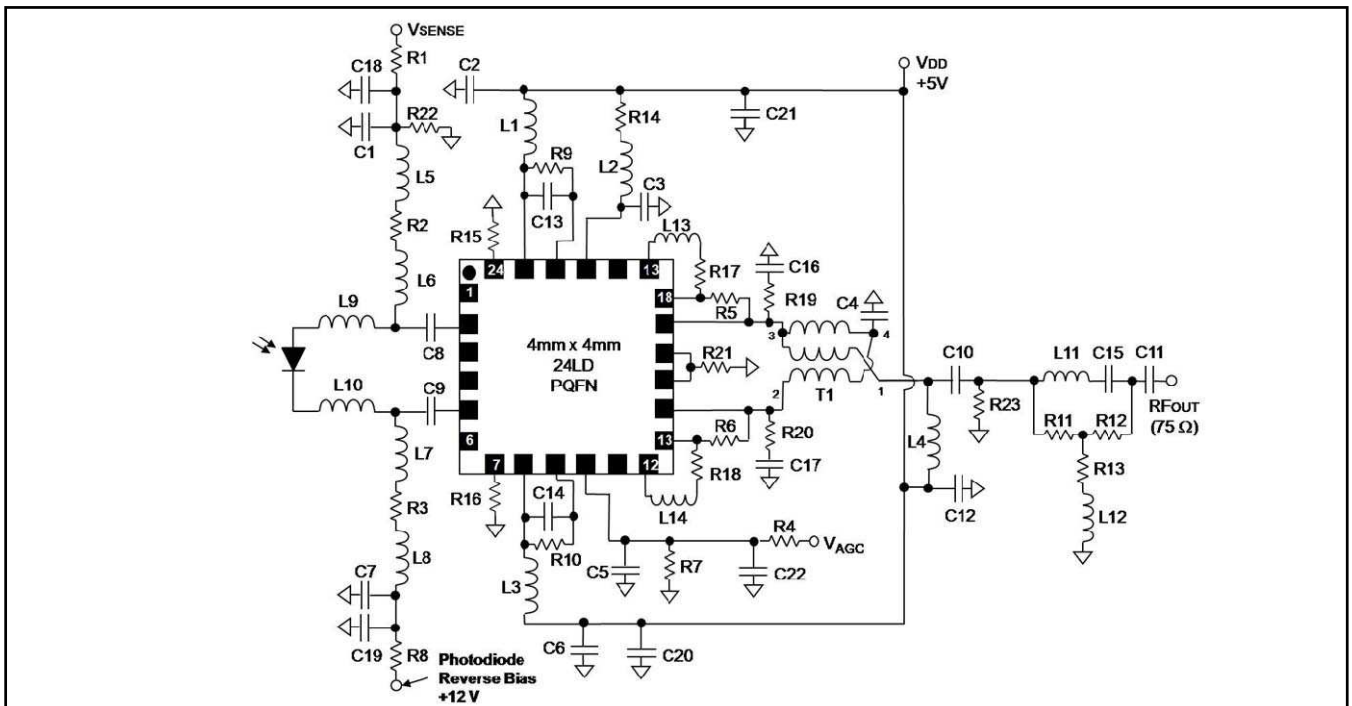
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## Recommended PCB



## Schematic Including Off-Chip Components



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## Optical Node RF Amplifier 50 - 1000 MHz

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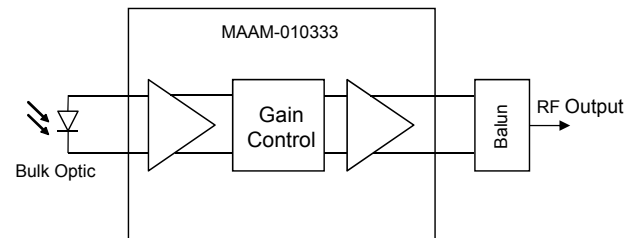
### Parts List

Component	Value	Case Style
L1 - L8 <sup>14</sup>	Ferrite Bead	0402
L9 - L10	12 nH w/w	0402
L11	8.2 nH	0402
L12	33 nH	0402
L13 - L14	10 nH	0402
C1 - C12	10 nF	0402
C13 - C14	2.7 pF	0402
C15	3.0 pF	0402
C16 - C17	2.0 pF	0402
C18 - C22	1.0 $\mu$ F	0603
R1 - R4	1 k $\Omega$	0402
R5 - R7	680 $\Omega$	0402
R8	200 $\Omega$	0402
R9 - R10	120 $\Omega$	0402
R11 - R12	39 $\Omega$	0402
R13	82 $\Omega$	0402
R14	180 $\Omega$	0402
R15 - R16	12 $\Omega$	0402
R17 - R18	47 $\Omega$	0402
R19 - R20	62 $\Omega$	0402
R21	6.2 $\Omega$	0402
R22	1 k $\Omega$	0603
R23	470 $\Omega$	0402
T1 <sup>15</sup>	1:1 Balun	SM-118A

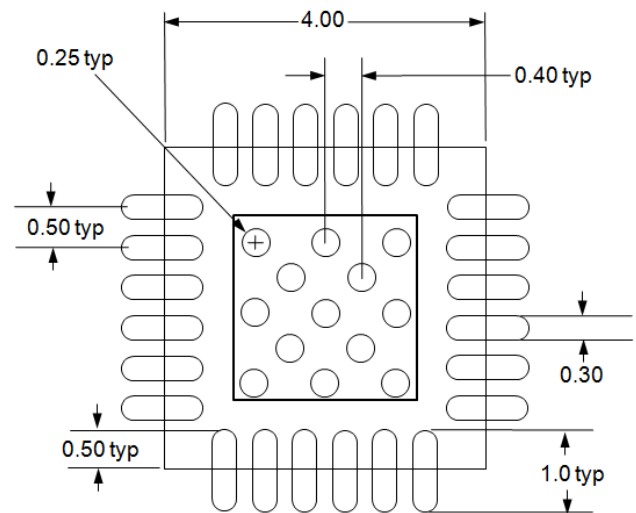
14. Ferrite Bead from Murata, part number BLM15HD182SN

15. M/A-COM Technology Solutions MABA-009210-CT1760  
1:1 T<sub>x</sub> Line Balun

### Application Schematic



### PCB Land Pattern



All dimension are in mm

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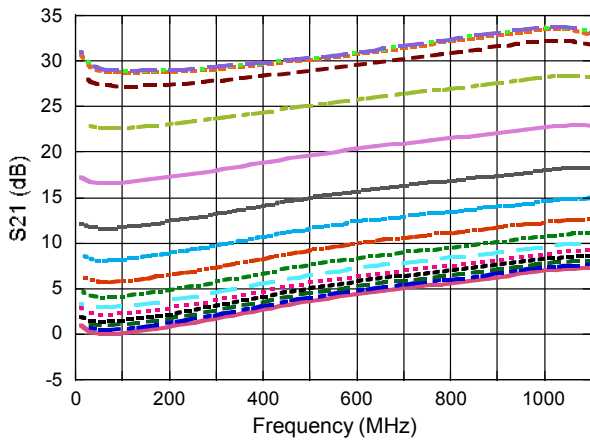
**Optical Node RF Amplifier**  
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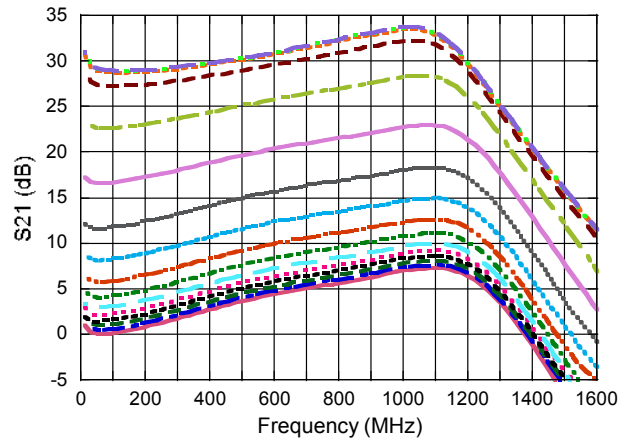
**Typical Performance Curves:**  
+25°C, VAGC = 0V to 3V in 0.2 V Steps



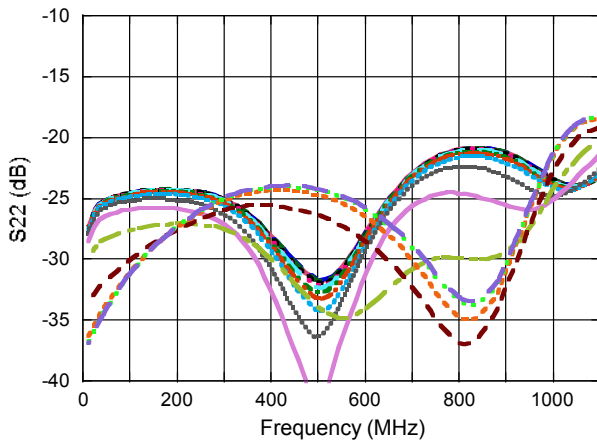
**Receiver Gain vs. Frequency to 1.1 GHz**



**Receiver Gain vs. Frequency to 1.6 GHz**



**Output Return Loss vs. Frequency**



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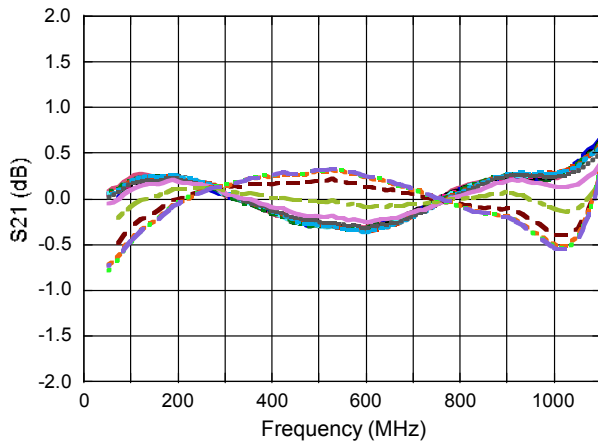
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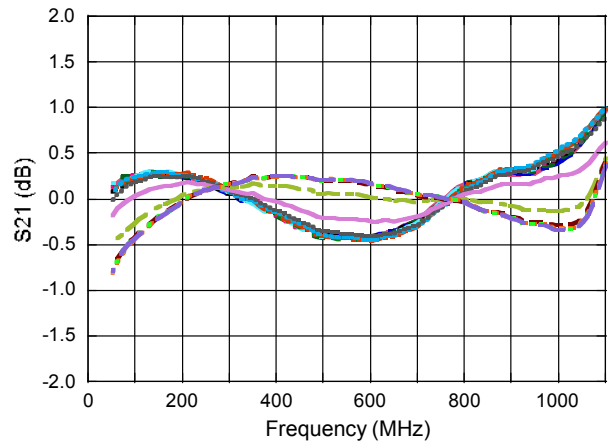
**Typical Performance Curves:**  
**VAGC = 0V to 3V in 0.2 V Steps**



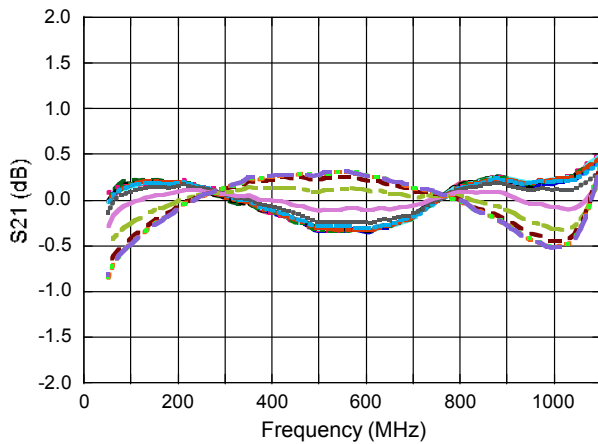
**Gain Flatness Deviation From Best Fit Line**  
**@ +25°C**



**Gain Flatness Deviation From Best Fit Line**  
**@ -40°C**

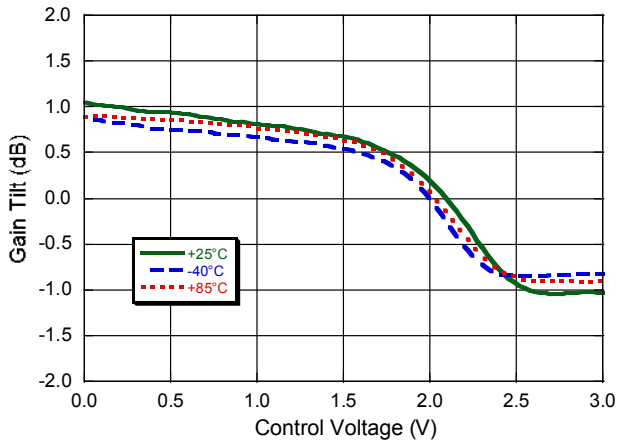


**Gain Flatness Deviation From Best Fit Line**  
**@ +85°C**

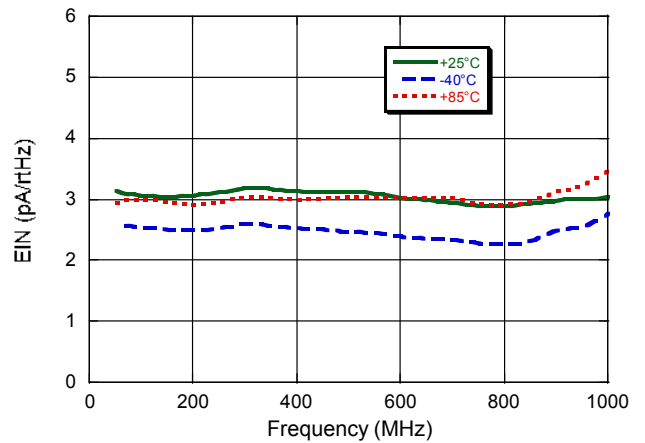


## Typical Performance Curves

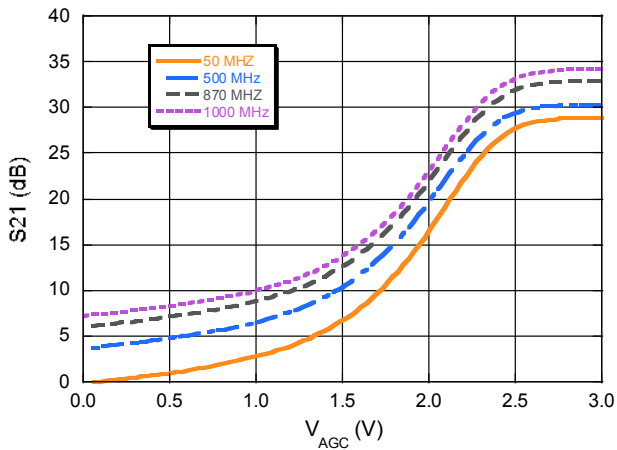
**Gain Tilt Deviation from Average Tilt**  
VAGC: 0V to 3V in 0.2 V Steps



**Equivalent Input Noise @ Max Gain**  
VAGC = 3V



**Receiver Gain vs. VAGC**  
VAGC = 0V to 3V in 0.2V Steps



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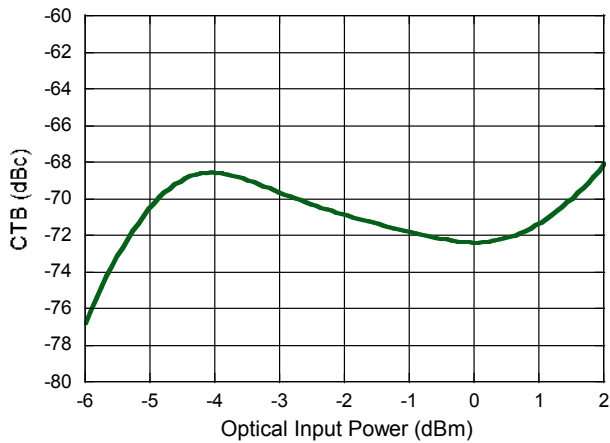
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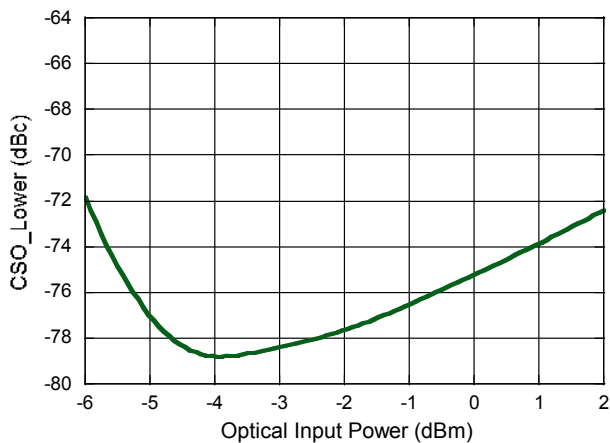
## Typical Performance Curves:

79 Channels; NTSC Frequency Plan Pout = +22.5 dBmV/ch @ 55 MHz; +24 dBmV @ 550 MHz

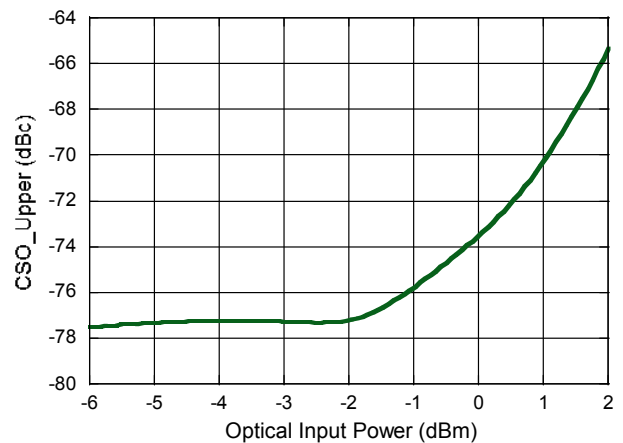
### CTB vs. Optical Input Power



### CSO\_Lower vs. Optical Input Power



### CSO\_Upper vs. Optical Input Power





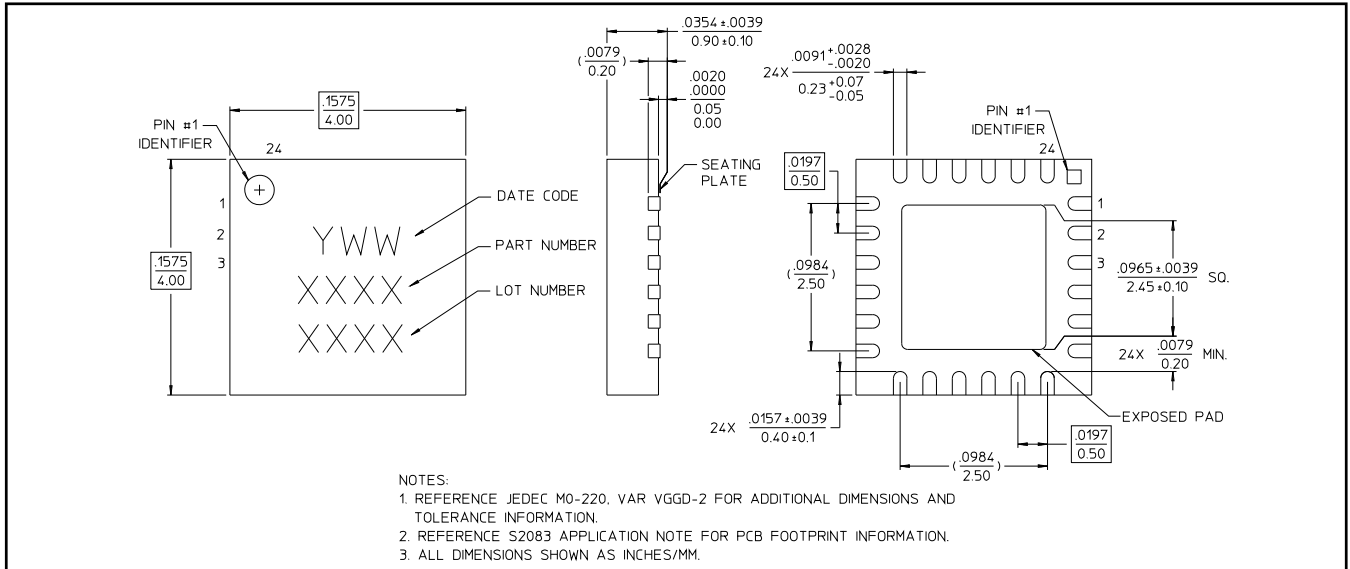
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## Lead Free 4 mm 24-lead PQFN<sup>†</sup>



<sup>†</sup> Reference Application Note 2083 for lead-free solder reflow recommendations.  
 Meets JEDEC moisture sensitivity level 1 requirements.  
 Plating is 100% matte tin over copper.